

DUAL LOW SIDE DRIVER

Features

- Gate drive supply range from 10.2 V to 20 V
- CMOS Schmitt-triggered inputs
- 3.3V and 5V logic compatible
- Two independent gate drivers
- Matched propagation delay for both channels
- Outputs out of phase with inputs
- Leadfree, RoHS compliant

Typical Applications

- General Purpose Dual Low Side Driver
- DC-DC converters

Product Summary

Topology	General Driver
V _{OUT}	10V - 20V
I _{o+} & I _{o-} (typical)	2.3A & 3.3A
t _{on} & t _{off} (typical)	50ns & 50ns

Package Type

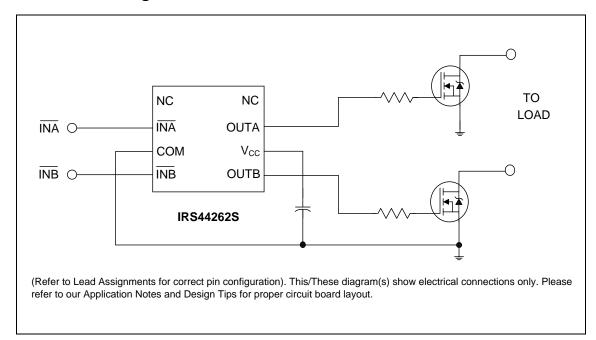


Ordering Information

Daniel Barri Namel and	Standard Pack		O	
Base Part Number	Package Type	Form	Quantity	Complete Part Number
ID 0 4 40000	801C8N	Tube/Bulk	95	IRS44262SPBF
IRS44262S	IRS44262S SOIC8N		2500	IRS44262STRPBF



Typical Connection Diagram



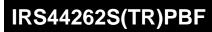
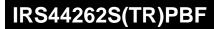




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Description

The IRS44262S is a low voltage, high speed power MOSFET and IGBT driver. Proprietary latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays between two channels are matched.

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Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage

Symbol	Definition	Min	Max	Units	
V _{cc}	Supply voltage	-0.3	20		
Vo	Output voltage	-0.3	V _{CC} + 0.3	V	
V _{IN}	Logic input voltage	-0.3	$V_{CC} + 0.3$		
P_D	Package power dissipation @ TA ≤ 25°C	_	0.625	W	
Rth _{JA}	Thermal resistance, junction to ambient — 200				
TJ	Junction temperature	ure 150			
Ts	Storage temperature	-55	150 °C		
T_L	Lead temperature (soldering, 10 seconds)	_	300		

parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Recommended Operating Conditions

For proper operation, the device should be used within the recommended conditions. All voltage parameters are absolute voltages referenced to COM unless otherwise stated in the table. The offset rating is tested with supply of $V_{CC} = 15V$.

Symbol	Definition	Min	Max	Units
V_{CC}	Supply voltage	11.2	20	
Vo	Output voltage	0	V _{CC}	V
V_{IN}	Logic input voltage	0	V_{CC}	
T_A	Ambient temperature	-40	125	°C



Static Electrical Characteristics

 V_{CC} = 15V, T_A = 25°C unless otherwise specified. The V_{IN} , and I_{IN} parameters are referenced to COM and are applicable to input leads: INA and INB. The V_O and I_O parameters are referenced to COM and are applicable to the output leads: OUTA and OUTB.

Symbol	Definition	Min	Тур	Max	Units	Test Conditions
V _{CCUV+}	Vcc supply undervoltage positive going threshold	9.2	10.2	11.2		
V _{CCUV} -	Vcc supply undervoltage negative going threshold	8.2	9.2	10.2	V	
V_{CCUVH}	Vcc supply undervoltage lockout hysteresis		1.0			
V_{IH}	Logic "0" input voltage (OUTA = LO, OUTB = LO)	2.5	_	1	V	
V _{IL}	Logic "1" input voltage (OUTA = HI, OUTB = HI)	_	_	0.8		
V _{OH}	High level output voltage, V _{BIAS} -V _O	l	_	1.4	V	$I_0 = 0 \text{ mA}$
V_{OL}	Low level output voltage, Vo	-	_	0.15		$I_O = 20 \text{ mA}$
I _{IN+}	Logic "1" input bias current	_	5	15	V _{IN} = 0V	
I _{IN-}	Logic "0" input bias current	-30	-10	_	μΑ	$V_{IN} = 5V$
I _{QCC}	Quiescent V _{CC} supply current		170	340		$V_{IN} = 0V \text{ or } 5V$
I _{O+}	Output high short circuit pulsed current		2.3		۸	$V_O=0V,\ V_{IN}=0V$
I _{O-}	Output low short circuit pulsed current	_	3.3	_	Α	$V_{O} = 15V, V_{IN} = 5V$

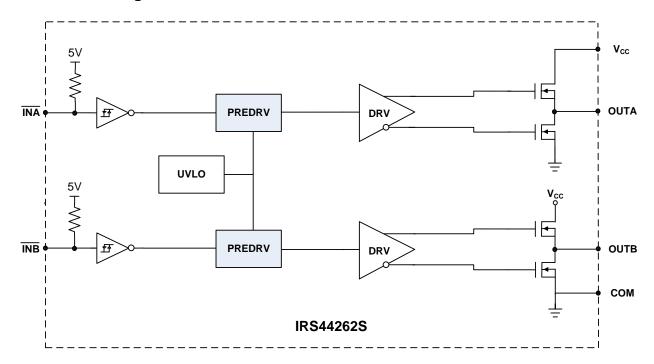
Dynamic Electrical Characteristics

 $V_{CC} = 15V$, $T_A = 25$ °C, and $C_L = 1000$ pF unless otherwise specified.

Symbol	Definition	Min	Тур	Max	Units	Test Conditions
t _{on}	Turn-on propagation delay	_	50	95		
$t_{\rm off}$	Turn-off propagation delay	_	50	95		Figure 0
t _r	Turn-on rise time	_	25	55	ns	Figure 2
t _f	Turn-off fall time	_	25	55		

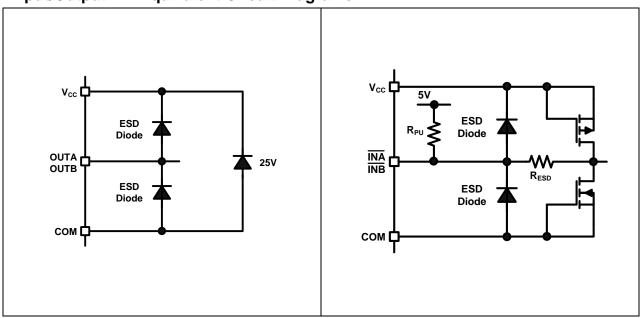


Functional Block Diagram





Input/Output Pin Equivalent Circuit Diagrams

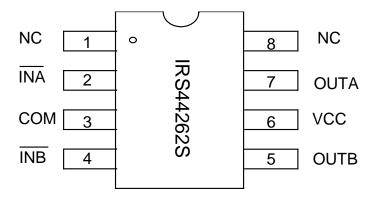




Lead Definitions

PIN	Symbol	Description			
1	NC	No connection			
2	ĪNĀ	Logic input for gate driver output (OUTA), out of phase			
3	COM	Ground			
4	INB	Logic input for gate driver output (OUTB), out of phase			
5	OUTB	Gate drive output B			
6	V _{CC}	Supply voltage			
7	OUTA	Gate drive output A			
8	NC	No connection			

Lead Assignments



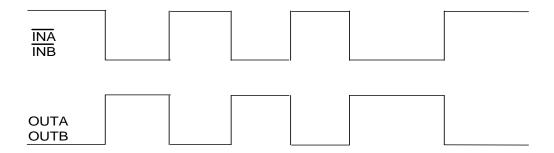


Figure 1: Input/output Timing Diagram

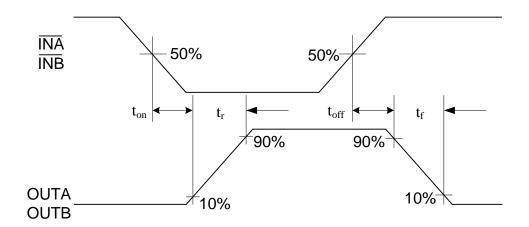


Figure 2: Switching Time Waveform Definitions

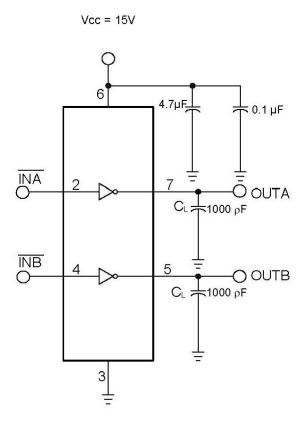
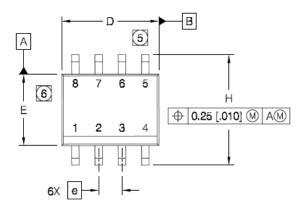
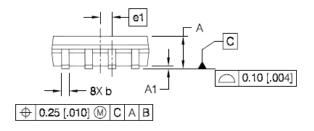


Figure 3: Switching Time Test Circuit

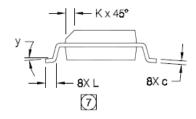


Package Details, SOIC8N



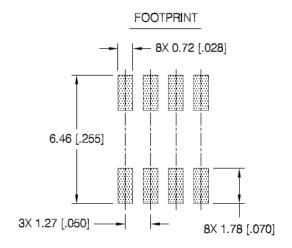


DIM	INC	HES	MILLIM	ETERS	
ואונם	MIN	MAX	MIN	MAX	
Α	.0532	.0688	1.35	1.75	
A1	.0040	.0098	0.10	0.25	
b	.013	.020	0.33	0.51	
C	.0075	.0098	0.19	0.25	
D	.189	.1968	4.80	5.00	
Е	.1497	.1574	3.80	4.00	
е	.050 B/	ASIC	1.27 BASIC		
e 1	.025 B/	ASIC	0.635	3ASIC	
Н	.2284	.2440	5.80	6.20	
K	.0099	.0196	0.25	0.50	
L	.016	.050	0.40	1.27	
У	0°	8°	0°	8°	



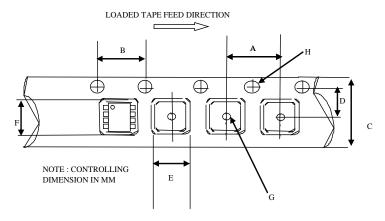
NOTES:

- DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
- 2. CONTROLLING DIMENSION: MILLIMETER
- 3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
- 4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
- (5) DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 [.006].
- (6) DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 [.010].
- (7) DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.



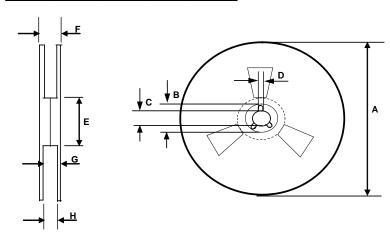


Package details: SOIC8N, Tape and Reel



CARRIER TAPE DIMENSION FOR 8SOICN

	Me	etric	Imp	erial
Code	Min	Max	Min	Max
Α	7.90	8.10	0.311	0.318
B C	3.90	4.10	0.153	0.161
С	11.70	12.30	0.46	0.484
D	5.45	5.55	0.214	0.218
E F	6.30	6.50	0.248	0.255
	5.10	5.30	0.200	0.208
G	1.50	n/a	0.059	n/a
Н	1.50	1.60	0.059	0.062

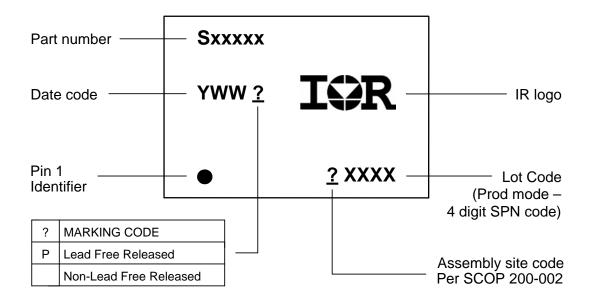


REEL DIMENSIONS FOR 8SOICN

	Metric		Imp	erial
Code	Min	Max	Min	Max
Α	329.60	330.25	12.976	13.001
В	20.95	21.45	0.824	0.844
С	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
Н	12.40	14.40	0.488	0.566



Part Marking Information





Qualification Information[†]

quantication information			
		Industrial ^{††}	
Qualification Level		Comments: This family of ICs has passed JEDEC's	
Qualification Level		Industrial qualification. IR's Consumer qualification level is	
		granted by extension of the higher Industrial level.	
Moisture Sensitivity Level		MSL2 ^{†††} 260°C	
		(per IPC/JEDEC J-STD-020)	
	Machine Model	Class B	
ESD	Machine Model	(per JEDEC standard JESD22-A115)	
ESD	Human Pady Madal	Class 2	
	Human Body Model	(per EIA/JEDEC standard EIA/JESD22-A114)	
IC Latch-Up Test		Class 1, Level A	
		(per JESD78)	
RoHS Compliant		Yes	

- † Qualification standards can be found at International Rectifier's web site http://www.irf.com/
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.
- ††† Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

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March 4, 2013

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